

Edition 1.0 2010-10

INTERNATIONAL STANDARD

NORME **INTERNATIONALE**



Measurement of quartz crystal unit parameters R F V F W Part 11: Standard method for the determination of the load resonance frequency $f_{\rm L}$ and the effective load capacitance $C_{\rm Leff}$ using automatic network analyzer techniques and error correction

https://standards.iteh.ai/catalog/standards/sist/054776ac-e53c-4347-b145-Mesure des paramètres des/résonateurs/à/quartz 10 Partie 11: Méthode normalisée pour la détermination de la fréquence de résonance à la charge fi et de la capacité de charge efficace CLeff utilisant des analyseurs automatiques de réseaux et correction des erreurs





THIS PUBLICATION IS COPYRIGHT PROTECTED

Copyright © 2010 IEC, Geneva, Switzerland

All rights reserved. Unless otherwise specified, no part of this publication may be reproduced or utilized in any form or by any means, electronic or mechanical, including photocopying and microfilm, without permission in writing from either IEC or IEC's member National Committee in the country of the requester.

If you have any questions about IEC copyright or have an enquiry about obtaining additional rights to this publication, please contact the address below or your local IEC member National Committee for further information.

Droits de reproduction réservés. Sauf indication contraire, aucune partie de cette publication ne peut être reproduite ni utilisée sous quelque forme que ce soit et par aucun procédé, électronique ou mécanique, y compris la photocopie et les microfilms, sans l'accord écrit de la CEI ou du Comité national de la CEI du pays du demandeur. Si vous avez des questions sur le copyright de la CEI ou si vous désirez obtenir des droits supplémentaires sur cette publication, utilisez les coordonnées ci-après ou contactez le Comité national de la CEI de votre pays de résidence.

IEC Central Office 3, rue de Varembé CH-1211 Geneva 20 Switzerland Email: inmail@iec.ch Web: www.iec.ch

About the IEC

The International Electrotechnical Commission (IEC) is the leading global organization that prepares and publishes International Standards for all electrical, electronic and related technologies.

About IEC publications

The technical content of IEC publications is kept under constant review by the IEC. Please make sure that you have the latest edition, a corrigenda or an amendment might have been published.

Catalogue of IEC publications: www.iec.ch/searchpub ARD PREVIEW

The IEC on-line Catalogue enables you to search by a variety of criteria (reference number, text, technical committee,...). It also gives information on projects, withdrawn and replaced publications.

IEC Just Published: www.iec.ch/online news/justpub
 Stay up to date on all new IEC publications. Just Published details twice a month all new publications released. Available on-line and also by email.

• Electropedia: <u>www.electropedia.drgds.iteh.ai/catalog/standards/sist/054776ac-e53c-4347-b145-</u> The world's leading online dictionary of electronic and electrical terms containing more than 20 000 terms and definitions in English and French, with equivalent terms in additional languages. Also known as the International Electrotechnical Vocabulary online.

Customer Service Centre: <u>www.iec.ch/webstore/custserv</u>

If you wish to give us your feedback on this publication or need further assistance, please visit the Customer Service Centre FAQ or contact us:

Email: <u>csc@iec.ch</u> Tel.: +41 22 919 02 11 Fax: +41 22 919 03 00

A propos de la CEI

La Commission Electrotechnique Internationale (CEI) est la première organisation mondiale qui élabore et publie des normes internationales pour tout ce qui a trait à l'électricité, à l'électronique et aux technologies apparentées.

A propos des publications CEI

Le contenu technique des publications de la CEI est constamment revu. Veuillez vous assurer que vous possédez l'édition la plus récente, un corrigendum ou amendement peut avoir été publié.

Catalogue des publications de la CEI: www.iec.ch/searchpub/cur_fut-f.htm

Le Catalogue en-ligne de la CEI vous permet d'effectuer des recherches en utilisant différents critères (numéro de référence, texte, comité d'études,...). Il donne aussi des informations sur les projets et les publications retirées ou remplacées.

Just Published CEI: www.iec.ch/online_news/justpub

Restez informé sur les nouvelles publications de la CEI. Just Published détaille deux fois par mois les nouvelles publications parues. Disponible en-ligne et aussi par email.

Electropedia: <u>www.electropedia.org</u>

Le premier dictionnaire en ligne au monde de termes électroniques et électriques. Il contient plus de 20 000 termes et définitions en anglais et en français, ainsi que les termes équivalents dans les langues additionnelles. Egalement appelé Vocabulaire Electrotechnique International en ligne.

Service Clients: <u>www.iec.ch/webstore/custserv/custserv_entry-f.htm</u>

Si vous désirez nous donner des commentaires sur cette publication ou si vous avez des questions, visitez le FAQ du Service clients ou contactez-nous:

Email: <u>csc@iec.ch</u> Tél.: +41 22 919 02 11

Fax: +41 22 919 03 00



Edition 1.0 2010-10

INTERNATIONAL STANDARD

NORME INTERNATIONALE



Measurement of quartz crystal unit parameters **REVIEW** Part 11: Standard method for the determination of the load resonance frequency $f_{\rm L}$ and the effective load capacitance $C_{\rm Leff}$ using automatic network analyzer techniques and error correction $_{\rm IEC.60444-11:2010}$

https://standards.iteh.ai/catalog/standards/sist/054776ac-e53c-4347-b145-

Mesure des paramètres des résonateurs à quartz Partie 11: Méthode normalisée pour la détermination de la fréquence de résonance à la charge f_{L} et de la capacité de charge efficace C_{Leff} utilisant des analyseurs automatiques de réseaux et correction des erreurs

INTERNATIONAL ELECTROTECHNICAL COMMISSION

COMMISSION ELECTROTECHNIQUE INTERNATIONALE

PRICE CODE CODE PRIX



ICS 31.140

ISBN 978-2-88912-210-3

 Registered trademark of the International Electrotechnical Commission Marque déposée de la Commission Electrotechnique Internationale

CONTENTS

FOF	FOREWORD				
1	Scope	5	5		
2	Norma	ative references5	5		
3	Gener	eneral concepts6			
	3.1	Load resonance frequencies <i>f</i> _{Lr} and <i>f</i> _{La} 6	3		
		Effective load capacitance C _{Leff} 6			
4	Reference plane and test conditions				
		General7			
		Principle of measurement7			
		Evaluation of errors			
Bibl	Bibliography14				
Figu	-igure 1 – Admittance of a quartz crystal unit6				
Figu	Figure 2 – X_{C} as a function of frequency (solid line) in the vicinity of f_{L}				
Figu	Figure 3 – Level of drive of a crystal in a π -network vs. frequency				
Figure 4 – Error of the load resonance frequency due to the inaccuracy of the measured voltages (dashed line) and the calibration resistances (soft line)					
Figı and	Figure 5 – C_L -error resulting from f_L error (due to inaccuracy of the measured voltages and the calibration resistances) for the same crystal as in Figure 411 Figure 6 – Frequency error due to noise of the measured voltages				
Figu	ure 6 –	Frequency error due to noise of the measured voltages12	2		
	Figure 7 – Error of load resonance fre <u>quency (f at 300</u> pF and 10 pF for typical equivalent paramet <mark>ers;of;quartz;crystahugits:</mark> dards/sist/054776ac-e53c-4347-b14512				
Figu	Figure 8 – Error of C _{Leff} for typical equivalent parameters of quartz crystal units				

INTERNATIONAL ELECTROTECHNICAL COMMISSION

MEASUREMENT OF QUARTZ CRYSTAL UNIT PARAMETERS –

Part 11: Standard method for the determination of the load resonance frequency $f_{\rm L}$ and the effective load capacitance $C_{\rm Leff}$ using automatic network analyzer techniques and error correction

FOREWORD

- 1) The International Electrotechnical Commission (IEC) is a worldwide organization for standardization comprising all national electrotechnical committees (IEC National Committees). The object of IEC is to promote international co-operation on all questions concerning standardization in the electrical and electronic fields. To this end and in addition to other activities, IEC publishes International Standards, Technical Specifications, Technical Reports, Publicly Available Specifications (PAS) and Guides (hereafter referred to as "IEC Publication(s)"). Their preparation is entrusted to technical committees; any IEC National Committee interested in the subject dealt with may participate in this preparatory work. International, governmental and non-governmental organizations liaising with the IEC also participate in this preparation. IEC collaborates closely with the International Organization for Standardization (ISO) in accordance with conditions determined by agreement between the two organizations.
- The formal decisions or agreements of IEC on technical matters express, as nearly as possible, an international consensus of opinion on the relevant subjects since each technical committee has representation from all interested IEC National Committees.
- 3) IEC Publications have the form of recommendations for international use and are accepted by IEC National Committees in that sense. While all reasonable efforts are made to ensure that the technical content of IEC Publications is accurate, IEC cannot be held responsible for the way in which they are used or for any misinterpretation by any end user.
- 4) In order to promote international uniformity, IEC National Committees undertake to apply IEC Publications transparently to the maximum extent possible (in4 their inational and regional publications. Any divergence between any IEC Publication and the corresponding national or regional publication shall be clearly indicated in the latter. 7dd12do08d5/inc 60444 11 2010
- the latter. 7dd12d2a98d5/iec-60444-11-2010
 5) IEC itself does not provide any attestation of conformity. Independent certification bodies provide conformity assessment services and, in some areas, access to IEC marks of conformity. IEC is not responsible for any services carried out by independent certification bodies.
- 6) All users should ensure that they have the latest edition of this publication.
- 7) No liability shall attach to IEC or its directors, employees, servants or agents including individual experts and members of its technical committees and IEC National Committees for any personal injury, property damage or other damage of any nature whatsoever, whether direct or indirect, or for costs (including legal fees) and expenses arising out of the publication, use of, or reliance upon, this IEC Publication or any other IEC Publications.
- 8) Attention is drawn to the Normative references cited in this publication. Use of the referenced publications is indispensable for the correct application of this publication.
- 9) Attention is drawn to the possibility that some of the elements of this IEC Publication may be the subject of patent rights. IEC shall not be held responsible for identifying any or all such patent rights.

International Standard IEC 60444-11 has been prepared by IEC technical committee 49: Piezoelectric, dielectric and electrostatic devices and associated materials for frequency control, selection and detection.

The text of this standard is based on the following documents:

CDV	Report on voting
49/852/CDV	49/883/RVC

Full information on the voting for the approval of this standard can be found in the report on voting indicated in the above table.

This publication has been drafted in accordance with the ISO/IEC Directives, Part 2.

A list of all parts of the IEC 60444 series under the general title *Measurement of quartz crystal unit parameters* can be found on the IEC website.

The committee has decided that the contents of this amendment and the base publication will remain unchanged until the stability date indicated on the IEC web site under "http://webstore.iec.ch" in the data related to the specific publication. At this date, the publication will be

- reconfirmed,
- withdrawn,
- replaced by a revised edition, or
- amended.

IMPORTANT – The 'colour inside' logo on the cover page of this publication indicates that it contains colours which are considered to be useful for the correct understanding of its contents. Users should therefore print this document using a colour printer.

iTeh STANDARD PREVIEW (standards.iteh.ai)

<u>IEC 60444-11:2010</u> https://standards.iteh.ai/catalog/standards/sist/054776ac-e53c-4347-b145-7dd12d2a98d5/iec-60444-11-2010

MEASUREMENT OF QUARTZ CRYSTAL UNIT PARAMETERS –

Part 11: Standard method for the determination of the load resonance frequency f_L and the effective load capacitance C_{Leff} using automatic network analyzer techniques and error correction

1 Scope

This part of IEC 60444 defines the standard method of measuring load resonance frequency $f_{\rm L}$ at the nominal value of $C_{\rm L}$, and the determination of the effective load capacitance $C_{\rm Leff}$ at the nominal frequency for crystals with the figure of merit M > 4.

M, according to Table 1 of IEC 60122-1:2002, is expressed in the following equation:

$$M = \frac{Q}{r} = \frac{1}{\omega C_0 R_1} \tag{1}$$

This gives good results in a frequency range up to 200 MHz. This method allows the calculation of load resonance frequency offset Δf_{L} , frequency pulling range $\Delta f_{L1,L2}$ and pulling sensitivity S as described in 2.2.31 of IEC 60122-1.2002. In contrary to the simple method of IEC 60444-4, this measurement technique avoids the use of physical load capacitors, and allows higher accuracy, better reproducibility and correlation to the application. It extends the upper frequency limit from 30MHz by the method of IEC 60444-4 to 200MHz approximately. This method is based on the error-corrected measurement technique of IEC 60444-5:1995, and therefore allows the measurement of f_L and C_{Leff} together with the determination of the equivalent crystal parameters in one sequence without changing the test fixture.

With this method the frequency $f_{\rm L}$ is searched where the reactance $X_{\rm C}$ of the crystal has the opposite value of the reactance of the load capacitance.

$$X_{\rm C} = -X_{\rm CL} = \frac{1}{\omega L C L}$$
(2)

Furthermore this method allows to determine the effective load capacitance C_{Leff} at the nominal frequency f_{nom} .

2 Normative references

The following referenced documents are indispensable for the application of this document. For dated references, only the edition cited applies. For undated references, the latest edition of the referenced document (including any amendments) applies.

IEC 60122-1:2002, Quartz crystal units of assessed quality – Part 1: Generic specification

IEC/TR 60444-4, Measurement of quartz crystal unit parameters by zero phase technique in a π -network – Part 4: Method for the measurement of the load resonance frequency f_L , load resonance resistance R_L and the calculation of other derived values of quartz crystal units, up to 30 MHz

IEC 60444-5:1995, Measurement of quartz crystal units parameters – Part 5: Methods for the determination of equivalent electrical parameters using automatic network analyzer techniques and error correction

3 General concepts

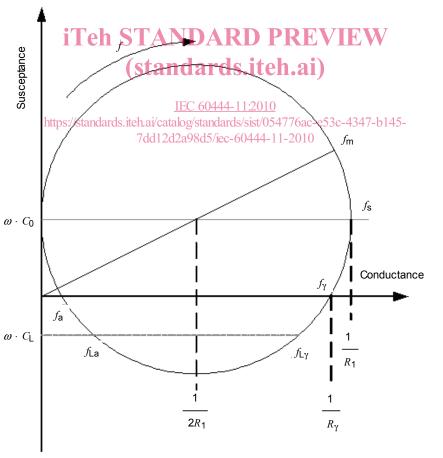
3.1 Load resonance frequencies f_{Lr} and f_{La}

As can be seen in Figure 1, there are two intersection frequencies where $X_{C} = -X_{CL}$, f_{Lr} with high admittance (low impedance) and f_{La} with low admittance (high impedance).

The load resonant frequency f_L is one of the two frequencies of a crystal unit in association with a series or with a parallel load capacitance, at which the electrical admittance (respectively impedance) of the combination is resistive. The load resonance frequency f_L is the lower of the two frequencies.

In a first approximation f_{L} can be calculated by:

$$\frac{1}{f_{\rm L}} \approx 2 \pi \sqrt{\frac{L_{\rm I}C_{\rm I} (C_{\rm 0} + C_{\rm L})}{C_{\rm I} + C_{\rm 0} + C_{\rm L}}}$$
(3)



IEC 2353/10

Figure 1 – Admittance of a quartz crystal unit

3.2 Effective load capacitance C_{Leff}

 C_{Leff} is defined by the reactance of the crystal at the nominal frequency

$$C_{\text{Leff}} = \frac{1}{\omega_{\text{nom}} X_{\text{C}}(\omega_{\text{nom}})}$$
(4)

Reference plane and test conditions 4

General 4.1

Reference plane: as in 8.4 of IEC 60444-5:1995.

Test conditions: crystal case not grounded.

Level of drive: the output level of the generator is set, such that at its (series) resonance frequency, the crystal under test is measured at the nominal drive level.

The measurement at the load resonance frequency using the method described below leads to a level of drive, which is remarkably lower than at the (series) resonance frequency due to the relative high reactance value. Therefore a correction measurement is performed, for details see 4.2.

4.2 **Principle of measurement**

The principles of measurement are the following. **iTeh STANDARD PREVIEW**

a) Calibration

Due to the high impedance measurements with this method special care has to be taken in the calibration of the test set-up.

Similar to IEC 60444-5:1995, use the following three known calibration elements:

- 1) short-circuit (0Ω) or resistor with low resistance 1/dd//d/sist/054776ac-e53c-4347-b145-
- 2) resistor of 25 Ω or 50 Ω nominal;
- 3) open circuit (infinite resistance) or capacitor of 10 pF nominal;

where Z_1 is the impedance of calibration element 1

 Z_2 is the impedance of calibration element 2

- Z_3 is the impedance of calibration element 3
- V_1 is the measured voltage with calibration element 1
- V_2 is the measured voltage with calibration element 2
- V_3 is the measured voltage with calibration element 3

The following parameters are then used for the measurement of quartz crystal units:

 R_{T} is the termination impedance of the π -network

Vs is the error-corrected "short" voltage

- Vo is the error-corrected "open" voltage
- b) Calibration with three known calibration elements:
 - 1) short-circuit calibration;
 - 2) calibration load (25 Ω or 50 Ω);
 - 3) open circuit calibration (or calibration capacitor of 10 pF);

$$RT = \frac{Z1Z2(V1 - V2) + Z2Z3(V2 - V3) + Z3Z1(V3 - V1)}{Z1(V2 - V3) + Z2(V3 - V1) + Z3(V2 - V2)}$$
(5)

$$VS = \frac{V3Z1Z2(V1 - V2) + V1Z2Z3(V2 - V3) + V2Z3Z1(V3 - V1)}{Z1Z2(V1 - V2) + Z2Z3(V2 - V3) + Z3Z1(V3 - V1)}$$
(6)

$$V_0 = \frac{Z_1 V_1 (V_2 - V_3) + Z_2 V_2 (V_3 - V_1) + Z_3 V_3 (V_1 - V_2)}{Z_1 (V_2 - V_3) + Z_2 (V_3 - V_1) + Z_3 (V_1 - V_2)}$$
(7)

NOTE If Z_3 is taken as infinite number (ideal open circuit), the above Equations (5), (6) and (7) result is not allowed divisions of infinite by infinite.

c) Measurement of a quartz crystal unit impedance Z_{c}

From the measured voltage with a quartz crystal unit V_c , the impedance Z_c of the quartz crystal unit is calculated with:

$$Zc = R \tau \frac{(V s - V c)}{(V c - V o)}$$
(8)

d) Measurement procedure for f_{L}

At load resonance frequency, the impedance of a quartz crystal unit is

$$Z_{\rm CL} = R_{\rm L} + jX_{\rm C} \tag{9}$$

For the determination of the load resonance frequency, the frequency f_{L} the lower frequency is searched for which Equation (2) is fulfilled, i.e.

$$\begin{array}{c} \text{ITeh STANDARD PREVIEW} \\ X_{C} + X_{CL} = 0 \\ \text{(standards, iteh, ai)} \end{array}$$
(10)

With network analyzers, the frequency f_{L} is easily determined by using «marker search». functions. IEC 60444-112010

e) Evaluation of Rhttps://standards.iteh.ai/catalog/standards/sist/054776ac-e53c-4347-b145-

The computation of the load resonance resistance $R_L^{2/4}$ from the real part of Z_c at the load resonance frequency f_L by the formula:

$$R_{\rm L} = R_{\rm c}(\omega_{\rm L}) = {\rm Re}(Z_{\rm c}(\omega_{\rm L})) \tag{11}$$

may result in excessive inaccuracy, because – especially for low frequency crystals – the angle of the voltage V_c is close to 90°.

Only for $\frac{X_{\text{CL}}}{R_{\text{L}}}$ < 10 this method yields reasonable results.

In all other cases, the R_1 should be computed from the equation given in IEC 60122-1:

$$R_{\rm L} = R_1 \left(1 + \frac{C_0}{C_{\rm L}} \right)^2 \tag{12}$$

f) Measurement procedure for C_{l eff}

The reactance $X_{c}(\omega_{nom})$ is measured at the nominal frequency and the effective load capacity C_{Leff} is then calculated with the following equation:

$$C \text{Leff} = \frac{1}{\omega \text{nom } XC(\omega \text{nom})}$$
(13)

Figure 2 shows X_{C} as a function of frequency (solid line) in the vicinity of f_{L} .

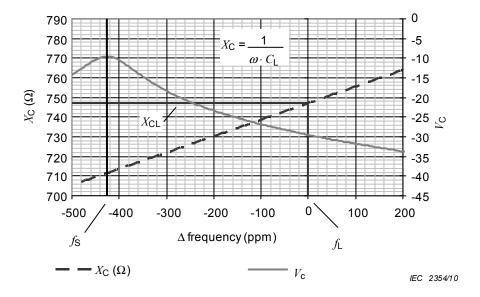


Figure 2 – X_{C} as a function of frequency (solid line) in the vicinity of f_{L}

g) Level of drive At the resonance frequency f_r , the level of drive P of a quartz crystal unit in a π -network is given by the voltage V_{xr} across the crystal ds.iteh.ai)

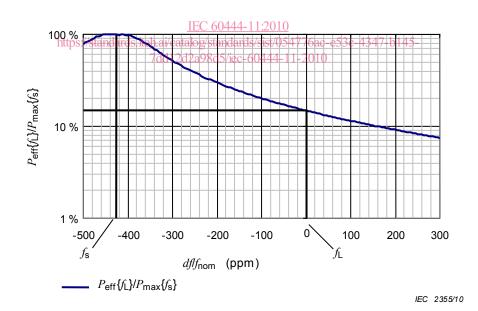


Figure 3 – Level of drive of a crystal in a π -network vs. frequency

with

$$P = \frac{V_{\rm xr}^2}{R_{\rm r}} \tag{14}$$

and

$$VXr = \frac{Vg Rr}{Rr + RT}$$
(15)

$$Vg = \sqrt{PRr} \frac{Rr + RT}{Rr}$$
(16)

At load resonance frequency f_L , the impedance Z_L of a quartz crystal unit is given by the load resonance resistance R_L and the modulus of the reactance of the load capacitor X_L :

- 10 -

$$|Z_{\rm L}| = \sqrt{R_{\rm L}^2 + X_{\rm L}^2}$$
(17)

and therefore the drive level is

$$P = \frac{V_{\rm xr}^2}{Z_{\rm L}^2}$$

$$V_{gL} = \sqrt{\mathbf{P} \cdot \mathbf{R}_{1}} \cdot \sqrt{\frac{X_{CL}^{2} \left(1 + X_{CL}^{2} + \left(R_{L} + R_{T}\right)^{2}\right)^{2} + R_{L}^{2} \left(\left(R_{L} + R_{T}\right)^{2} - 1\right)}{R_{L}^{2} + X_{CL}^{2}}}$$
(18)

In order to get the same level of drive at the load frequency $f_{\rm L}$ as at the series resonance frequency $f_{\rm S}$, it is necessary to increase the output power of the generator by the ratio:

$$ABS\begin{bmatrix} V_{\text{gL}} \\ V_{\text{gr}} \end{bmatrix} = \sqrt{\frac{Rr}{RL}} \frac{\sqrt{(RL + RT)^2 + XCL^2}}{RL}$$
(19)

NOTE If the required power cannot be reached by the generator, a second measurement at resonance frequency f_r is performed with a by factor $ABS\left(\frac{V_{gL}}{V_{gr}}\right)$ lower level and the difference of both series resonance measurements is added to the load resonance frequency f_L is added to the load resonance frequency f_L and f_L is added to the load resonance frequency f_L and f_L is added to the load resonance frequency f_L and f_L is added to the load resonance frequency f_L and f_L is added to the load resonance frequency f_L and f_L is added to the load resonance frequency f_L and f_L is added to the load resonance frequency f_L and f_L is a first of the load resonance frequency f_L and f_L is a first of the load resonance frequency f_L and f_L is a first of the load resonance frequency f_L and f_L is a first of the load resonance frequency f_L and f_L is a first of the load resonance frequency f_L and f_L is a first of the load resonance frequency f_L and f_L is a first of the load resonance frequency f_L and f_L is a first of the load resonance frequency f_L and f_L is a first of the load resonance frequency f_L is a first of the load resonance frequency f_L and f_L is a first of the load resonance frequency f_L is a first of the load resonance frequency f_L and f_L is a first of the load resonance frequency f_L and f_L is a first of the load resonance frequency f_L and f_L and f_L is a first of the load resonance frequency f_L and f_L a

Evaluation of errors 4.3

a) General comments

According to the application of quartz crystal units in oscillators, the measurement accuracy of the load resonance frequency $f_{\rm L}$ is presented here. The accuracy of the load capacitance C_{Leff} can be calculated then from the frequency accuracy and the equivalent parameters of the crystal C_0 and C_1 from the relation

$$\frac{f_{\rm L} - f_{\rm s}}{f_{\rm s}} = \frac{C_{\rm 1}}{2(C_{\rm 0} + C_{\rm L})} \tag{20}$$

b) Accuracy of measurement

The accuracy of the measurement is given by the calibration resistors and the measured voltages. In order to achieve an accuracy of the voltages of 1 %, it may be necessary to calibrate the test equipment in the whole power range.